



NF-02-PE(Si24R1) Specification

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1. Product Overview

NF-02-PE (Si24R1) is a wireless, integrated 2.4G module. The module is embedded with the Si24R1 RF chip and power amplifier chip, with a transmitting power up to 20dBm; and transmission rate of up to 2Mbps, with a standard SPI communication interface, cost-effective. The module adopts 2.54mm standard pin interface, convenient assembly, and can be quickly applied to various terminal products.

NF-02-PE (Si24R1) is suitable for a variety of Internet of Things occasions, widely used in wireless mouse, wireless remote control, motion sensing equipment, active RFID,NFC, low power self-hoc network wireless sensor nodes, etc.



图1芯片架构图

1.1. Characteristics

- DIP-8 ultra-small size package, simple to use
- Using the GFSK / FSK modulation mode
- Support for the 2Mbps/1Mbps/250Kbps data rate
- Wide power supply voltage range: 2.0~3.6V
- Channel: 126 RF Channels
- Receive sensitivity: -96dBm@250kbps
- Max. emission power: 20dBm

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- Four-wire SPI interface for up to 10Mbps
- Internal integrated intelligent ARQ base-band protocol engine
- Send and receiving data hardware interrupt output
- Support for 1bit RSSI output

1.2. Main parameters

Table 1 main parameter descriptions

| Model Name NF-02-PE (Si24R1) | | |
|--|--|--|
| Package DIP-8 | | |
| Size | 40.8*15.3*19.0(±0.2)mm | |
| Antenna | SMA external antenna | |
| Frequency Range | 2400~2525MHz | |
| Modulation mode | GFSK/FSK | |
| Emission power | Max 20dBm | |
| Data Rate | Support 2Mbps/1Mbps/250Kbps | |
| Channel | 126 RF channels, each channel apart 1MHz | |
| Test Distance | 1000meters(Clear, no obstacle, and maximum emission power) | |
| Operating Temperature-40°C ~ 85°C | | |
| Store Temperature | e $-40 \sim 125^{\circ}C, <90\%RH$ | |
| Receive sensitivity | -96dBm@250Kbps | |
| Emission lengthIndividual Data Package 1~32 bytes, 3 class FIFO | | |
| Receive length | Individual Data Package 1~32 bytes, 3 class FIFO | |
| Power supply range | Voltage supply 2.0V~3.6V, current supply>250mA | |
| Standby current | 26μΑ | |



| Receive current | 25mA(2Mbps) |
|----------------------|-----------------|
| Emission current | 250mA(20dBm) |
| Support Interface | SPI |
| Interface Rate | SPI 最高速率 10Mbps |

1.3. Electrical parameters

NF-02-PE (Si24R1) module is electrostatic sensitive devices and special precautions need to be taken when handling



Picture 2 ESD Anti-static diagram

1.4. Electrical characteristics

Table 2. Description of Electrical Characteristics and Parameters

| Parameters | | Conditions | Min | Typical values | Max | Unit |
|------------|----------------------------------|------------|------------------|-------------------|---------------------|------|
| Voltage | | VDD | 2.0 | 3.3 | 3.6 | V |
| I/O | V _{IL} /V _{IH} | - | -0.3/0.75VD D | - | 0.25VDD/VDD+0. 3 | V |
| | Vol/Voh | - | N/0.8VIO | - | 0.1VIO/N | V |

1.5. 2.4G RF Performance

Table 3: Description of Electrical Characteristics and Parameters

|--|



 $\rm NF{-}02{-}\rm PE$ (Si24R1) Specification V1.0

| Operating frequency | 2400-2525 | MHz | | |
|----------------------|-----------|-----|--|--|
| Output power | | | | |
| Maximum output power | 20±2 | dBm | | |
| Receive sensitivity | | | | |
| 2Mbps | -83±2 | dBm | | |
| 1Mbps | -87±2 | dBm | | |
| 250kbps | -96±2 | dBm | | |

2. Appearance and dimensions



Figure 3 module diagram (pictures for reference only)





Figure 4 Module Size

3. Pin definition



Figure 5 Pin definition diagram Table 4 Pin Function Definition

| Pin No. | Name | Function |
|---------|------|--|
| 1 | VCC | Power supply, which must be between 2.0~3.6V |
| 2 | GND | Ground wire, connected to the power supply reference |



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| | | ground |
|---|------|--|
| 3 | CSN | Block select pin to start a SPI communication |
| 4 | CE | Module enable control pin, CE at low level in standby mode |
| 5 | MOSI | Module SPI data input pin |
| 6 | SCK | Module SPI bus clock |
| 7 | IRQ | Module interrupt signal output, low level effective |
| 8 | MISO | Module SPI data output pin |

4. Application circuit



Figure 6 Application Circuit

4.1. Application Instructions

- It is recommended that the CE pin connect to the GPIO port of the MCU.
- IRQ is not connected to obtain the interrupt state of the STATUS register by SPI query. However, it is recommended to use the hardware external interrupt of the MCU, let the IRQ connect to the single chip computer external trigger pins, trigger the single chip computer interrupt.
- The RF chip model used by NF-02-PA (Si24R1) is to read and write the Si24R1, chip register according to the chip manual, see the Si24R1 chip manual or download sample STM32 and 51 drivers on the official website.
- Pay attention to good grounding, large area paving, small power ripple, increase filter capacitance and be as close to GND pins of module VCC as far as possible.



Other model selection of 2.4G refer to this web: <u>https://docs.ai-thinker.com/2.4g</u>

5. Design guidance

5.1. Notes

- High frequency analog devices have static sensitive characteristics, please avoid human contact with electronic components on the module.
- Ensure that the power supply must have a small ripple and avoid the large beating of the supply voltage value, the type π filter (ceramic capacitance / / tan capacitor + inductance) is recommended.
- The module ground uses a single point ground mode, recommended 0 Euro resistance, or 0mH inductance, and the other circuits are referenced separated.
- Whether the antenna nearby is covered by a metal shell, some components will affect the performance of the antenna, such as relays, and also need to ensure that the antenna is exposed, preferably vertical upward.
- If there are other wireless modules in the same product, reasonable frequency planning and shielding measures are required to reduce the influence of harmonic interference and intermodulation interference.
- If there is present near the module circuit board, increase the linear distance between the module and the crystal as possible.

5.2. Power supply

- Recommended 3.3V voltage with peak current above 250mA.
- LDO power supply is recommended; if DC-DC recommends ripple control within 30mV.
- The DC-DC power supply circuit recommends reserving the position of the dynamic response capacitance to optimize the output ripple when the load changes greatly.
- The 3.3V power interface is recommended to add ESD devices.



5.3. FAQ

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| No. | Reason | Description |
|-----|------------------------|---|
| 01 | obstacle | Due to 2.4G its physical characteristics and poor penetration, the communication distance will be greatly shorter |
| 02 | Interference source | Temperature, humidity and electromagnetic wave interference at the same frequency end will lead to an increase in the packet loss rate of communication |
| 03 | Antenna | The antenna uses a 50 ohm impedance walk line that causes signal attenuation with a metal object near the antenna or by placing the module in the shield cover |
| 04 | CE pin | Failure to keep transmitter at high level in program configuration causes reduced sensitivity when accepting response model |
| 05 | Emission power | With the register configuration, the higher the transmit power configuration, the farther the transmit |
| 06 | Emission power | If the configured emission rate is too high, the emission distance is relatively reduced |
| 07 | Low voltage | Power supply voltage less than 3.3v, causes insufficient power supply of the module and relatively affects the transmitting power of the module |

Table 5. Communication distance is very close, not reaching the ideal distance

Table 6 Heat damage e heating damage

| No. | Reason | Description | |
|-----|-----------------------|--|--|
| 01 | Supply voltage | Check the power supply to ensure between 2.0~3.6V, cause over 3.6 V causes module damage. | |
| 02 | Stability | Check the stability of the power supply, and the voltage cannot fluctuate too much | |
| 03 | Antistatic protection | Ensure anti-static operation during power installation and use, and high-frequency devices have static sensitivity | |
| 04 | Welding | Module cannot pass re-flow and peak welding or it will be damage | |



6. Package information

The package of NF-02-PE (Si24R1) is in anti-static bag.



Figure 7 Packaging Diagram

7. Contact us

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